

N-Channel Power MOSFET

600V, 20A, 196mΩ

FEATURES

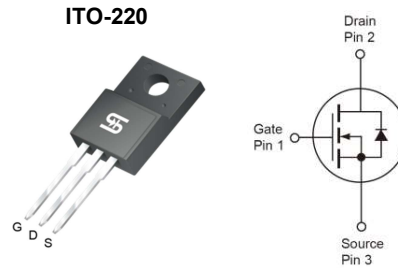
- Super-Junction technology
- High performance, small $R_{DS(on)} \cdot Q_g$ figure of merit (FOM)
- High ruggedness performance
- 100% UIS & R_g tested
- High commutation performance
- ROHS Compliant
- Halogen-free according to IEC 61249-2-21

KEY PERFORMANCE PARAMETERS

PARAMETER	VALUE	UNIT
V_{DS}	600	V
$R_{DS(on)}$ (max)	196	mΩ
Q_g	38	nC

APPLICATIONS

- Power Supply
- AC/DC LED Lighting



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	600	V
Gate-Source Voltage		V _{GS}	±30	V
Continuous Drain Current ^(Note 1)	T _C = 25°C	I _D	20	A
	T _C = 100°C		12	A
Pulsed Drain Current ^(Note 2)		I _{DM}	60	A
Total Power Dissipation @ T _C = 25°C		P _D	70	W
Single Pulse Avalanche Energy ^(Note 3)		E _{AS}	450	mJ
Single Pulse Avalanche Current ^(Note 3)		I _{AS}	4.2	A
Operating Junction and Storage Temperature Range		T _J , T _{STG}	- 55 to +150	°C

THERMAL PERFORMANCE

PARAMETER	SYMBOL	MAXIMUM	UNIT
Junction to Case Thermal Resistance	$R_{\theta JC}$	1.8	$^\circ\text{C/W}$
Junction to Ambient Thermal Resistance	$R_{\theta JA}$	62	$^\circ\text{C/W}$

Thermal Performance Note: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 1mA$	BV_{DSS}	600	--	--	V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 1mA$	$V_{GS(TH)}$	3	4.3	5	V
Gate Body Leakage	$V_{GS} = \pm 30V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 600V, V_{GS} = 0V$	I_{DSS}	--	--	1	μA
Drain-Source On-State Resistance (Note 4)	$V_{GS} = 10V, I_D = 9.5A$	$R_{DS(on)}$	--	170	196	m Ω
Dynamic (Note 5)						
Total Gate Charge	$V_{DS} = 300V, I_D = 20A,$ $V_{GS} = 10V$	Q_g	--	39	--	nC
Gate-Source Charge		Q_{gs}	--	12	--	
Gate-Drain Charge		Q_{gd}	--	18	--	
Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ $f = 1.0MHz$	C_{iss}	--	1534	--	pF
Output Capacitance		C_{oss}	--	1373	--	
Reverse Transfer Capacitance		C_{rss}	--	56	--	
Gate Resistance	$f = 1.0MHz$	R_g	--	1.9	3.8	Ω
Switching (Note 6)						
Turn-On Delay Time	$V_{DD} = 300V, R_G = 10\Omega,$ $I_D = 10A, V_{GS} = 10V,$	$t_{d(on)}$	--	31	--	ns
Turn-On Rise Time		t_r	--	31	--	
Turn-Off Delay Time		$t_{d(off)}$	--	56	--	
Turn-Off Fall Time		t_f	--	12	--	
Source-Drain Diode						
Body-Diode Continuous Forward Current		I_S	--	--	20	A
Body-Diode Pulsed Current		I_{SM}	--	--	60	A
Forward Voltage (Note 4)	$I_S = 20A, V_{GS} = 0V$	V_{SD}	--	--	1.5	V
Reverse Recovery Time	$I_S = 20A$	t_{rr}	--	411	--	ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q_{rr}	--	8.13	--	μC

Notes:

- Current limited by package.
- Pulse width limited by the maximum junction temperature.
- $L = 50mH, I_{AS} = 4.2A, V_{DD} = 50V, R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
- Pulse test: $PW \leq 300\mu s$, duty cycle $\leq 2\%$.
- For DESIGN AID ONLY, not subject to production testing.
- Switching time is essentially independent of operating temperature.

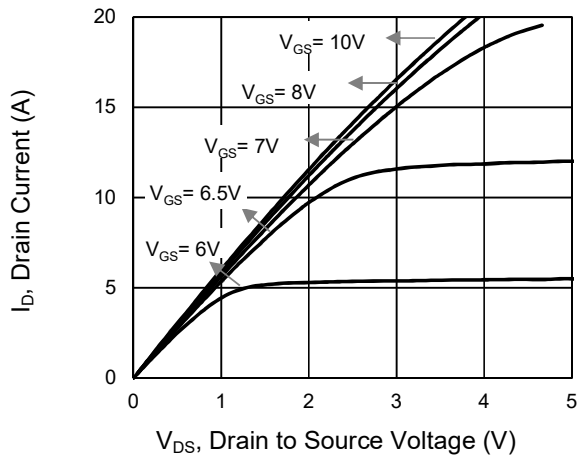
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TSM60NC196CI C0G	ITO-220	50pcs / Tube

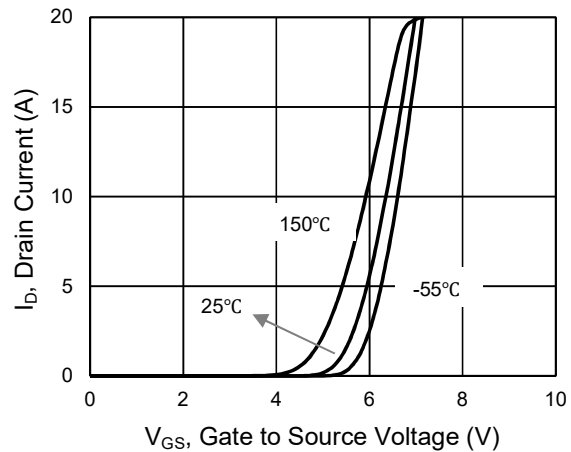
CHARACTERISTICS CURVES

($T_C = 25^\circ\text{C}$ unless otherwise noted)

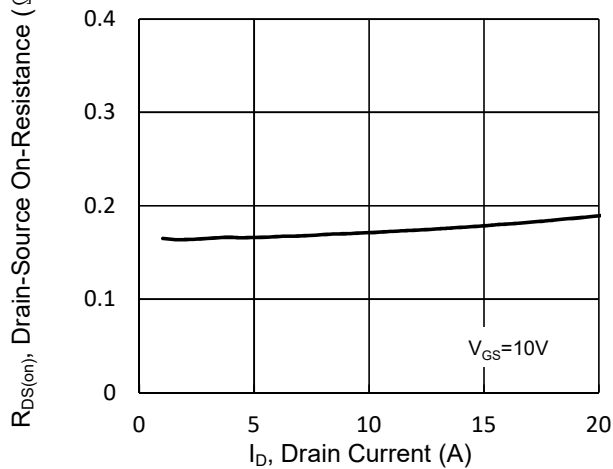
Output Characteristics



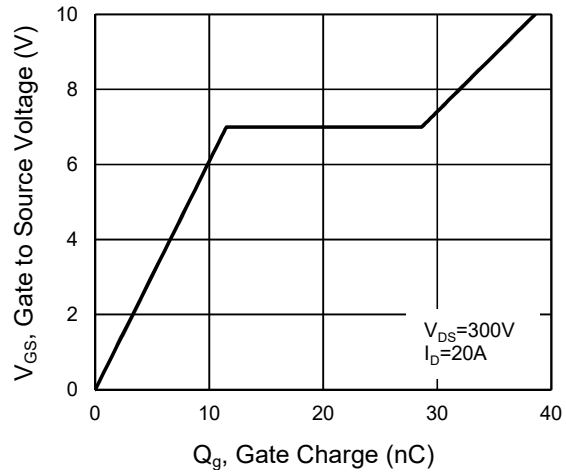
Transfer Characteristics



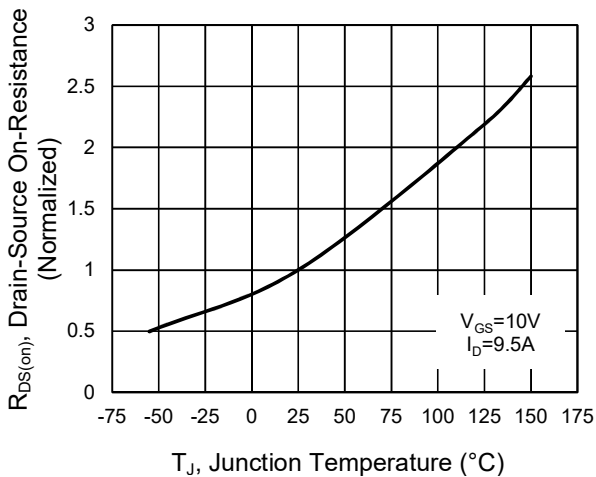
On-Resistance vs. Drain Current



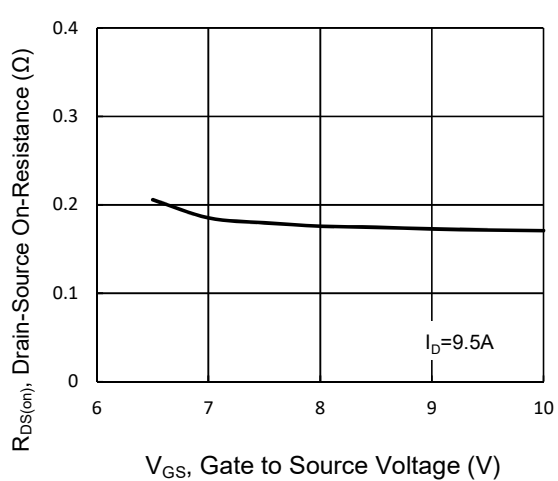
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature

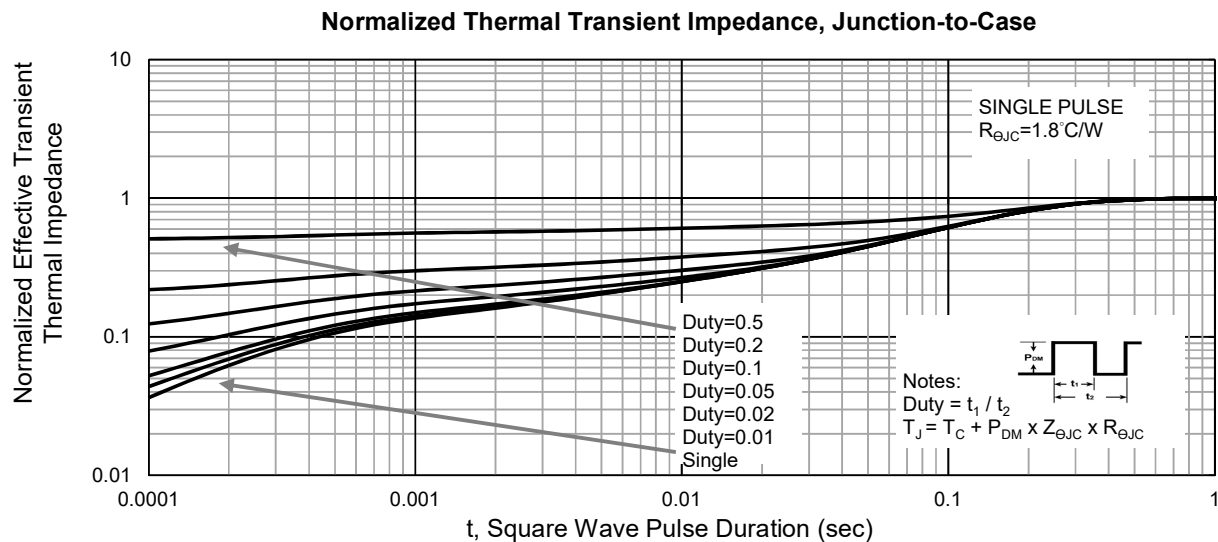
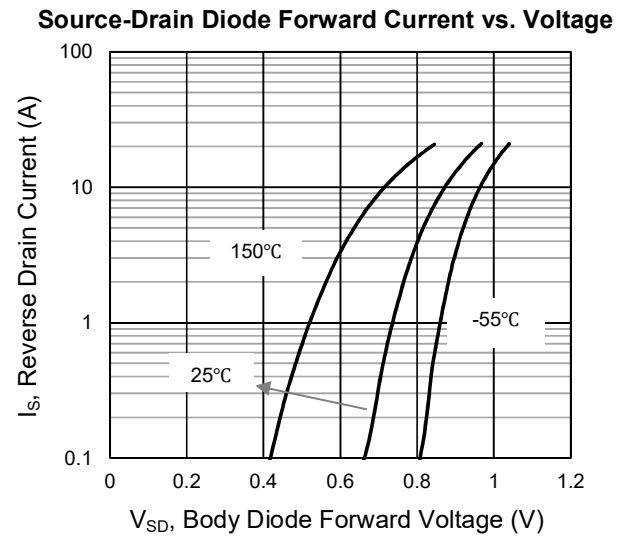
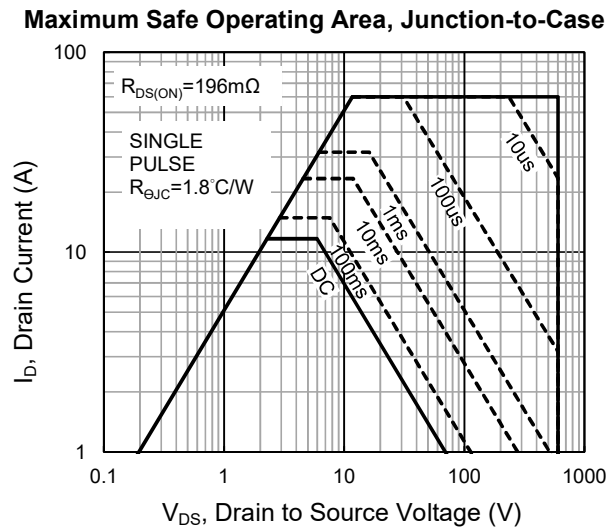
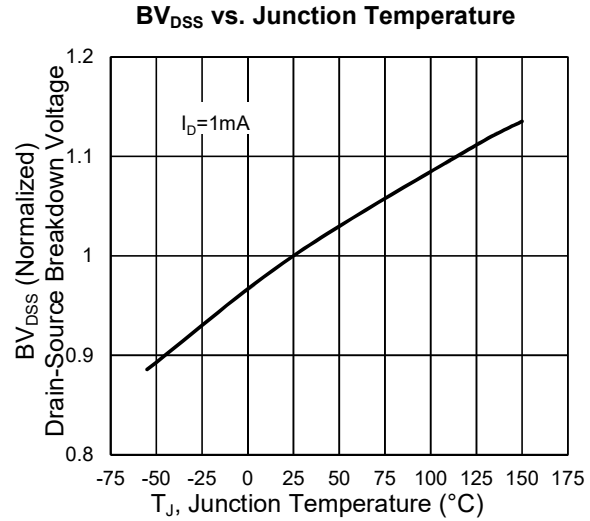
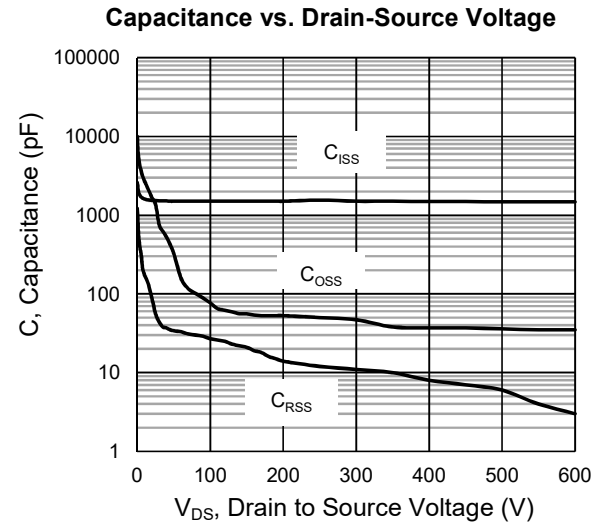


On-Resistance vs. Gate-Source Voltage



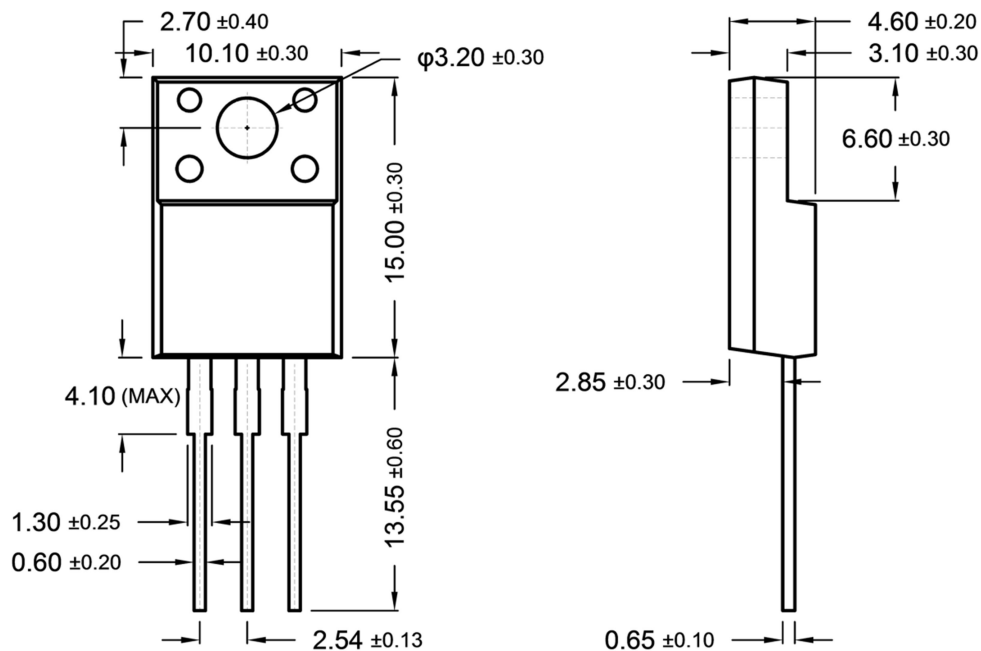
CHARACTERISTICS CURVES

($T_C = 25^\circ\text{C}$ unless otherwise noted)

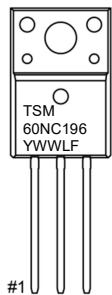


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

ITO-220



MARKING DIAGRAM



- Y** = Year Code
- WW** = Week Code (01~52)
- L** = Lot Code (1~9, A~Z)
- F** = Factory Code

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